NSN 5962-01-317-3178

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Between 0.357 inches and 0.432 inches

Body Length:

1.490 inches

Body Width:

Between 0.500 inches and 0.610 inches

Body Height:

Between 0.172 inches and 0.217 inches

Maximum Power Dissipation Rating:

1.0 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Training set, countermeasures signals an/msr-t4

Features Provided:

Hermetically sealed and burn in and static operation and low power

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

26 input

Case Outline Source And Designator:

D-10 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 70.0 volts power source

Time Rating Per Chacteristic:

45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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